

Uni-directional 4.5V High Capacitance TVS

Description

The PTVSHC2EN4V5U Transient Voltage Suppressor is designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebook computers, and PDA's. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, lower operating voltage, lower clamping voltage and no device degradation when compared to MLVs. The PTVSHC2EN4V5U protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. The PTVSHC2EN4V5U is available in a DFN1610-2L package with working voltages of 4.5 volt.



Feature

- \rightarrow 1300W Peak pulse power per line (t_P = 8/20 μ s)
- DFN1610-2L package
- Response time is typically < 1 ns</p>
- Protect one I/O or power line
- Low clamping Voltage
- RoHS compliant
- Transient protection for data lines to IEC 61000-4-2(ESD)
 ±30KV(air), ±30KV(contact); IEC 61000-4-4 (EFT) 40A (5/50ns)
 IEC 61000-4-5 (Lightning) 70A (8/20us)

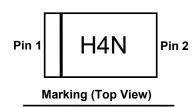
Pin 1 Circuit Diagram

Applications

- Cell phone handsets and accessories
- Personal digital assistants (PDA's)
- Notebooks, desktops, and servers
- Portable instrumentation
- Cordless phones
- Digital cameras

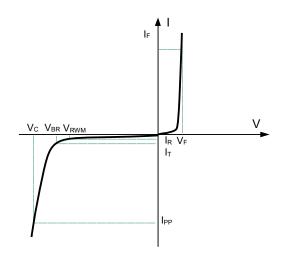
MP3 players

- Peripherals
- Mechanical Characteristics
- Lead finish:100% matte Sn(Tin)
- Mounting position: Any
- ➤ Qualified max reflow temperature:260°C
- Pure tin plating: 7 ~ 17 um
- ➤ Pin flatness:≤3mil



Electronics Parameter

Symbol	Parameter	
V _{RWM}	Peak Reverse Working Voltage	
I _R	Reverse Leakage Current @ V _{RWM}	
V_{BR}	Breakdown Voltage @ I _T	
I _T	Test Current	
IPP	Maximum Reverse Peak Pulse Current	
Vc	Clamping Voltage @ I _{PP}	
P _{PP}	Peak Pulse Power	
CJ	Junction Capacitance	
I _F	Forward Current	
V _F	Forward Voltage @ I _F	



Electrical characteristics per line@25℃(unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Peak Reverse Working Voltage	V _{RWM}				4.5	V
Breakdown Voltage	V _{BR}	I _t =1mA	5		7	V
Reverse Leakage Current	I _R	V _{RWM} =4.5V			5	μA
Clamping Voltage	Vc	I _{PP} =70A t _P = 8/20μs		11	12	V
Clamping Voltage	Vc	I _{PP} =100A t _P = 8/20μs		13	14	V
Junction Capacitance	Cj	V _R =0V f = 1MHz	760	860	960	pF

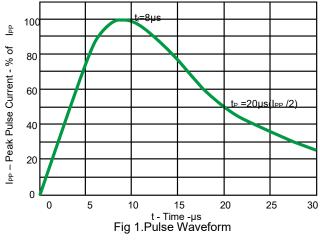
Absolute maximum rating@25℃

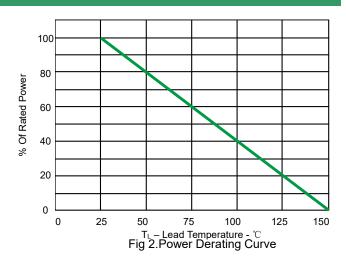
Rating	Symbol	Value	Units
Peak Pulse Power (t _P = 8/20µs)	P _{pp}	1300	W
Peak Pulse Current (t _P = 8/20µs)	I _{pp}	100	А
Lead Soldering Temperature	T∟	260 (10 sec)	°C
Operating Temperature	TJ	-55 to 125	$^{\circ}$
Storage Temperature	T _{STG}	-55 to 150	$^{\circ}$

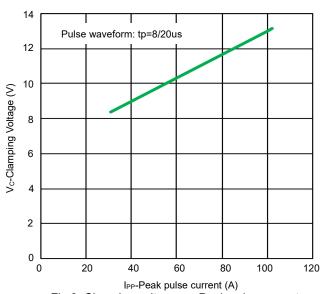
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ESD Protector PTVSHC2EN4V5U









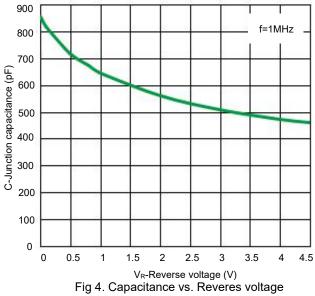
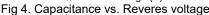
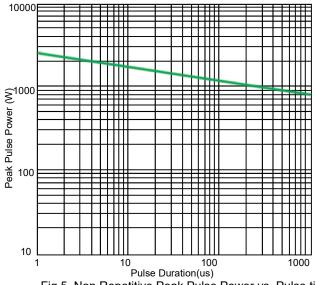


Fig 3. Clamping voltage vs. Peak pulse current





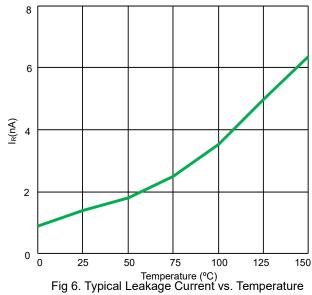
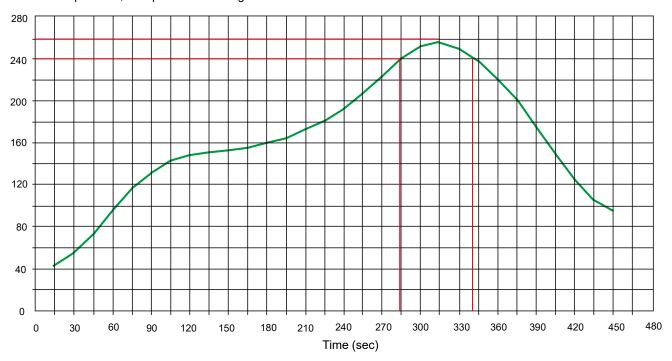


Fig 5. Non Repetitive Peak Pulse Power vs. Pulse time

ESD Protector PTVSHC2EN4V5U

Solder Reflow Recommendation

Peak Temp=257°C, Ramp Rate=0.802deg. °C/sec



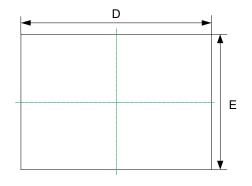
PCB Design

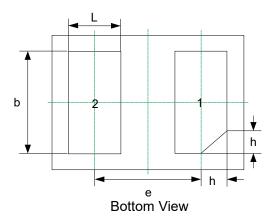
For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

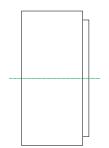
- Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- Do not make false economies and save copper for the ground connection.
- Place via holes to ground as close as possible to the anode of the TVS diode.
- > Use as many via holes as possible for the ground connection.
- Keep the length of via holes in mind! The longer the more inductance they will have.

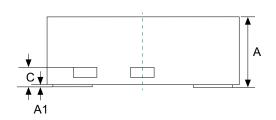
ESD Protector PTVSHC2EN4V5U

Product dimension (DFN1610-2L)

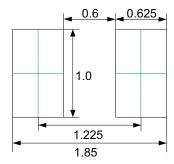








Dim	Millimeters		
	MIN	MAX	
А	0.45	0.60	
A1		0.05	
b	0.75	0.85	
С	0.10	0.20	
D	1.55	1.65	
е	1.10BSC		
E	0.95	1.05	
L	0.35	0.45	
h	0.15	0.25	



Recommended Soldering Pad

Unit:mm

Ordering information

Device	Package	Reel	Shipping
PTVSHC2EN4V5U	DFN1610-2L (Pb-Free)	7"	3000 / Tape & Reel

ESD Protector PTVSHC2EN4V5U

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